







**SN54AHCT373, SN74AHCT373** 

## SCLS239O - OCTOBER 1995 - REVISED AUGUST 2024

# **SNx4AHCT373 Octal Transparent D-Type Latches With 3-State Outputs**

## 1 Features

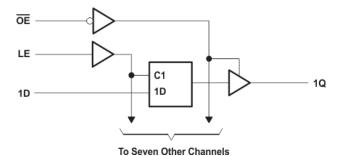
- Inputs are TTL-voltage compatible
- Latch-up performance exceeds 250mA per JESD

## 2 Description

The 'AHCT373 devices are octal-transparent D-type latches. When the latch-enable (LE) input is high, the Q outputs follow the data (D) inputs. When LE is low, the Q outputs are latched at the logic levels of the D inputs.

#### **Device Information**

PART NUMBER	PACKAGE <sup>(1)</sup>	PACKAGE SIZE(2)	BODY SIZE(3)
	J (CDIP, 20)	24.2mm x 7.62mm	24.2mm × 6.92mm
SN54AHCT373	W (CFP, 20)	13.09mm x 8.13mm	13.09mm × 6.92mm
	FK (LCCC, 20)	8.89mm × 8.89mm	8.89mm × 8.89mm
	DB (SSOP, 20)	7.2mm × 7.8mm	7.50mm x 5.30mm
	DW (SOIC, 20)	12.80mm × 10.3mm	12.8mm x 7.5mm
SN74AHCT373	NS (SOP, 20)	12.60mm x 7.8mm	12.6mm x 5.30mm
	N (PDIP, 20)	24.33mm x 9.4mm	25.40mm x 6.35mm
	PW (TSSOP, 20)	6.50mm × 6.4mm	6.50mm x 4.40mm



**Logic Diagram (Positive Logic)** 

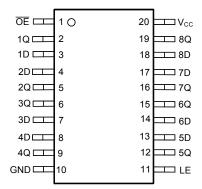


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## 3 Pin Configuration and Functions



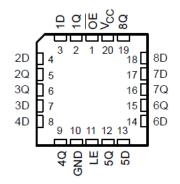


Figure 3-1. SN54AHCT373 J or W Package; SN74AHCT373 DB, DGV, DW, N, NS, or PW Package (Top View)

Figure 3-2. SN54AHCT373 FK Package (Top View)

**Table 3-1. Pin Functions** 

	PIN	1/0	250200500				
NO.	NAME	I/O	DESCRIPTION				
1	ŌĒ	1	Output Enable				
2	1Q	0	1Q Output				
3	1D	ı	1D Input				
4	2D	ı	2D Input				
5	2Q	0	2Q Output				
6	3Q	0	3Q Output				
7	3D	ı	3D Input				
8	4D	ı	4D Input				
9	4Q	0	4Q Output				
10	GND	_	Ground				
11	LE	I	Latch Enable				
12	5Q	0	5Q Output				
13	5D	ı	5D Input				
14	6D	ı	6D Input				
15	6Q	0	6Q Output				
16	7Q	0	7Q Output				
17	7D	1	7D Input				
18	8D	1	8D Input				
19	8Q	0	8Q Output				
20	V <sub>CC</sub>	_	Power Pin				



## 4 Specifications

## 4.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range		-0.5	7	V
VI	Input voltage range <sup>(2)</sup>		-0.5	7	V
Vo	Output voltage range <sup>(2)</sup>		-0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>1</sub> < 0		-20	mA
I <sub>OK</sub>	Output clamp current	$V_O < 0$ or $V_O > V_{CC}$		±20	mA
Io	Continuous output current	$V_O = 0$ to $V_{CC}$		±25	mA
	Continuous current through V <sub>CC</sub> or GND			±75	mA
T <sub>stg</sub>	Storage temperature		-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

## 4.2 ESD Ratings

			Value	UNIT
		Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	±2000	
V <sub>(ESD)</sub>	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup>	±1000	V

<sup>(1)</sup> JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

## 4.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)(1)

		SN54AH	CT373	SN74A	HCT373	UNIT
		MIN	MAX	MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage	4.5	5.5	4.5	5.5	V
V <sub>IH</sub>	High-level input voltage	2		2		V
V <sub>IL</sub>	Low-level input voltage		0.8		0.8	V
VI	Input voltage	0	5.5	0	5.5	V
Vo	Output voltage	0	V <sub>CC</sub>	0	V <sub>cc</sub>	V
I <sub>OH</sub>	High-level output current		-8		-8	mA
I <sub>OL</sub>	Low-level output current		8		8	mA
Δt/Δν	Input transition rise or fall rate		20		20	ns/V
T <sub>A</sub>	Operating free-air temperature	-55	125	-40	85	°C

All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs (SCBA004).

<sup>(2)</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>(2)</sup> JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



### 4.4 Thermal Information

		SN74AHCT373							
THERMAL METRIC(1)		DW (SOIC)	DB (SSOP)	DGV (TVSOP)	N (PDIP)	NS (SOP)	PW (TSSOP)	UNIT	
		20 PINS							
$R_{\theta JA}$	Junction-to-ambient thermal resistance	58	70	92	69	60	116.8	°C/W	

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report (SPRA953).

#### 4.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V	T <sub>A</sub> = 25°C			SN54AHCT373		SN74AHCT373		UNIT
PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII
V	I <sub>OH</sub> = -50 μA	4.5 V	4.4	4.5		4.4		4.4		V
V <sub>OH</sub>	I <sub>OH</sub> = -8 mA	4.5 V	3.94			3.8		3.8		V
V	I <sub>OL</sub> = 50 μA	4.5 V			0.1		0.1	,	0.1	V
V <sub>OL</sub>	I <sub>OL</sub> = 8 mA	4.5 V			0.36		0.44	,	0.44	V
I <sub>OZ</sub>	V <sub>O</sub> = V <sub>CC</sub> or GND	5.5 V			± 0.25		± 2.5	,	± 2.5	μΑ
I <sub>I</sub>	V <sub>I</sub> = 5.5 V or GND	0 V to 5.5 V			±0.1		± 1 <sup>(1)</sup>		±1	μΑ
I <sub>CC</sub>	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			4		40		40	μA
ΔΙ <sub>CC</sub> †	One input at 3.4 V,Other inputs at V <sub>CC</sub> or GND	5.5 V			1.35		1.5		1.5	mA
C <sub>i</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND	5 V		4	10	,			10	pF
Co	V <sub>O</sub> = V <sub>CC</sub> or GND	5 V		9						pF

<sup>(1)</sup> On products compliant to MIL-PRF-38535, this parameter is not production tested at  $V_{CC} = 0 \text{ V}$ .

## 4.6 Timing Requirements, V<sub>CC</sub> = 5 V ± 0.5 V

over recommended operating free-air temperature range (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

	PARAMETER		T <sub>A</sub> = 25°C		SN54AHCT373		SN74AHCT373	
	PARAIVIE I ER	MIN	MAX	MIN	MAX	MIN	MAX	UNIT
t <sub>w</sub>	Pulse duration, LE high	6.5		6.5		6.5		ns
t <sub>su</sub>	Setup time, data before LE↓	1.5		1.5		1.5		ns
t <sub>h</sub>	Hold time, data after LE↓	3.5		3.5		3.5		ns



## 4.7 Switching Characteristics, $V_{CC} = 5 V \pm 0.5 V$

over recommended operating free-air temperature range (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	FROM	то	LOAD	T <sub>A</sub>	= 25°C		SN54AH	CT373	SN74AH	СТ373	UNIT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII
t <sub>PLH</sub>	- D	Q	C <sub>1</sub> = 15 pF		5.1 <sup>(1)</sup>	8.5 <sup>(1)</sup>	1 <sup>(1)</sup>	9.5 <sup>(1)</sup>	1	9.5	ns
t <sub>PHL</sub>		Q	C <sub>L</sub> = 15 pr		5.1 <sup>(1)</sup>	8.5 <sup>(1)</sup>	1 <sup>(1)</sup>	9.5 <sup>(1)</sup>	1	9.5	115
t <sub>PLH</sub>	LE	Q	C <sub>L</sub> = 15 pF		7.7 <sup>(1)</sup>	12.3 <sup>(1)</sup>	1 <sup>(1)</sup>	13.5 <sup>(1)</sup>	1	13.5	ns
t <sub>PHL</sub>		Q	C <sub>L</sub> = 15 pr		7.7 <sup>(1)</sup>	12.3 <sup>(1)</sup>	1 <sup>(1)</sup>	13.5 <sup>(1)</sup>	1	13.5	115
t <sub>PZH</sub>	- ŌĒ Q	0	C <sub>L</sub> = 15 pF		6.3 <sup>(1)</sup>	10.9 <sup>(1)</sup>	1 <sup>(1)</sup>	12.5 <sup>(1)</sup>	1	12.5	ns
t <sub>PZL</sub>		Q	C <sub>L</sub> = 15 pr		6.3 <sup>(1)</sup>	10.9 <sup>(1)</sup>	1 <sup>(1)</sup>	12.5 <sup>(1)</sup>	1	12.5	115
t <sub>PHZ</sub>	ŌĒ	Q	C <sub>L</sub> = 15 pF		6 <sup>(1)</sup>	10.2 <sup>(1)</sup>	1 <sup>(1)</sup>	11 <sup>(1)</sup>	1	11	ns
t <sub>PLZ</sub>			Q	C <sub>L</sub> = 15 pr		6 <sup>(1)</sup>	10.2 <sup>(1)</sup>	1 <sup>(1)</sup>	11 <sup>(1)</sup>	1	11
t <sub>PLH</sub>	- D	Q	C <sub>L</sub> = 50 pF		5.9	9.5	1	10.5	1	10.5	no
t <sub>PHL</sub>		Q	C <sub>L</sub> = 50 pr		5.9	9.5	1	10.5	1	10.5	ns
t <sub>PLH</sub>	LE	Q	C <sub>1</sub> = 50 pF		8.5	13.3	1	14.5	1	14.5	ns
t <sub>PHL</sub>		Q	C <sub>L</sub> = 50 pr		8.5	13.3	1	14.5	1	14.5	115
t <sub>PZH</sub>	- OE	Q	C <sub>L</sub> = 50 pF		7.1	11.9	1	13.5	1	13.5	ns
t <sub>PZL</sub>	- OE	Q	CL = 30 pi		7.1	11.9	1	13.5	1	13.5	115
t <sub>PHZ</sub>	ŌĒ	Q	C <sub>L</sub> = 50 pF		6.8	11.2	1	12	1	12	ns
t <sub>PLZ</sub>		Q	CL = 30 pr		6.8	11.2	1	12	1	12	115
t <sub>sk(o)</sub>			C <sub>L</sub> = 50 pF			1 <sup>(2)</sup>				1	ns

<sup>(1)</sup> On products compliant to MIL-PRF-38535, this parameter is not production tested.

### 4.8 Noise Characteristics

 $V_{CC} = 5 \text{ V}, C_L = 50 \text{ pF}, T_A = 25^{\circ}\text{C}^{(1)}$ 

	PARAMETER	SN74	UNIT		
	FARAMETER	MIN	TYP	MAX	ONII
V <sub>OL(P)</sub>	Quiet output, maximum dynamic V <sub>OL</sub>		0.8	1.2	V
V <sub>OL(V)</sub>	Quiet output, minimum dynamic V <sub>OL</sub>		-0.8	-1.2	V
V <sub>OH(V)</sub>	Quiet output, minimum dynamic V <sub>OH</sub>	4.1			V
V <sub>IH(D)</sub>	High-level dynamic input voltage	2			V
$V_{IL(D)}$	Low-level dynamic input voltage			8.0	V

(1) Characteristics are for surface-mount packages only.

## 4.9 Operating Characteristics

 $V_{CC}$  = 5 V, T <sub>A</sub> = 25°C

	PARAMETER	TES	T CONDITIONS	TYP	UNIT
$C_{pd}$	Power dissipation capacitance	No load,	f = 1 MHz	17	pF

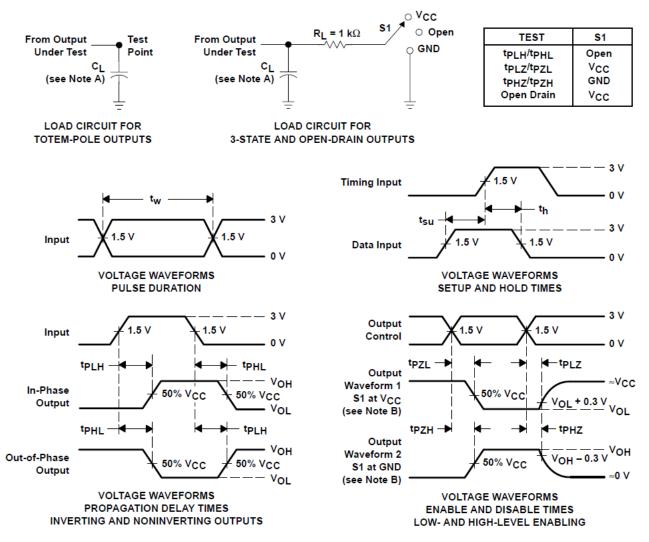
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<sup>(2)</sup> On products compliant to MIL-PRF-38535, this parameter does not apply.



### **5 Parameter Measurement Information**



NOTES: A. C<sub>1</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz, Z  $_{O}$  = 50  $\Omega$ ,  $t_{r} \leq$  3 ns,  $t_{f} \leq$  3 ns.
- D. The outputs are measured one at a time with one input transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

Figure 5-1. Load Circuit and Voltage Waveforms



## **6 Detailed Description**

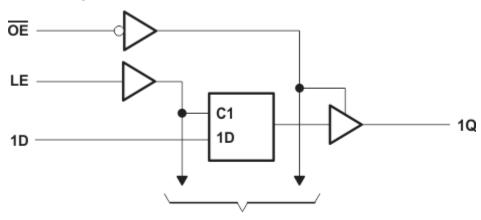
### 6.1 Overview

A buffered output-enable  $(\overline{OE})$  input can be used to place the eight outputs in either a normal logic state (high or low) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without interface or pullup components.

 $\overline{\text{OE}}$  does not affect the internal operations of the latches. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

## 6.2 Functional Block Diagram



To Seven Other Channels

Figure 6-1. Logic Diagram (Positive Logic)

#### 6.3 Device Functional Modes

Table 6-1. Function Table (Each Latch)

ı	INPUTS	OUTPUT	
ŌĒ	LE	Q	
L	Н	Н	Н
L	Н	L	L
L	L	Χ	$Q_0$
Н	Х	Х	Z



## 7 Application and Implementation

## 7.1 Power Supply Recommendations

The power supply can be any voltage between the MIN and MAX supply voltage rating located in the *Recommended Operating Conditions* table.

Each  $V_{CC}$  pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, 0.1  $\mu$ f is recommended; if there are multiple  $V_{CC}$  pins, then 0.01  $\mu$ f or 0.022  $\mu$ f is recommended for each power pin. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. A 0.1  $\mu$ f and a 1  $\mu$ f are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

### 7.2 Layout

## 7.2.1 Layout Guidelines

When using multiple bit logic devices inputs should not ever float. In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input AND gate are used or only three of the four buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Specified below are the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or  $V_{CC}$  whichever make more sense or is more convenient. Floating outputs is generally acceptable, unless the part is a transceiver. If the transceiver has an output enable pin it will disable the outputs section of the part when asserted. This will not disable the input section of the I.O's so they also cannot float when disabled.

### 7.2.2 Layout Example

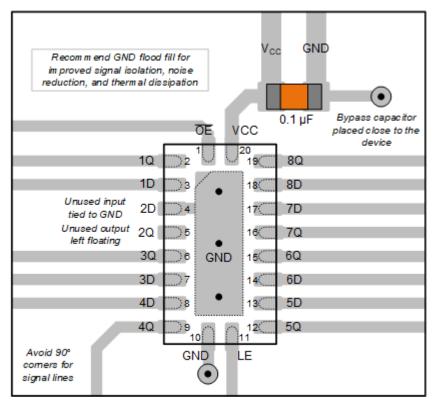


Figure 7-1. Layout Diagram



## 8 Device and Documentation Support

## 8.1 Documentation Support (Analog)

#### 8.1.1 Related Documentation

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 8-1. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
SN54AHCT373	Click here	Click here	Click here	Click here	Click here
SN74AHCT373	Click here	Click here	Click here	Click here	Click here

### 8.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

## 8.3 Support Resources

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

#### 8.4 Trademarks

TI E2E<sup>™</sup> is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

#### 8.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### 8.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

#### 9 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

## 

### Changes from Revision M (July 2023) to Revision N (August 2023)

Page

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## 10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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### **PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9686701Q2A	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9686701Q2A SNJ54AHCT 373FK	Samples
5962-9686701QRA	ACTIVE	CDIP	J	20	20	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9686701QR A SNJ54AHCT373J	Samples
5962-9686701QSA	ACTIVE	CFP	W	20	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9686701QS A SNJ54AHCT373W	Samples
SN74AHCT373DBR	ACTIVE	SSOP	DB	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HB373	Samples
SN74AHCT373DW	OBSOLETE	SOIC	DW	20		TBD	Call TI	Call TI	-40 to 85	AHCT373	
SN74AHCT373DWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AHCT373	Samples
SN74AHCT373N	ACTIVE	PDIP	N	20	20	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	SN74AHCT373N	Samples
SN74AHCT373NSR	ACTIVE	SOP	NS	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AHCT373	Samples
SN74AHCT373PW	OBSOLETE	TSSOP	PW	20		TBD	Call TI	Call TI	-40 to 85	HB373	
SN74AHCT373PWR	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HB373	Samples
SNJ54AHCT373FK	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9686701Q2A SNJ54AHCT 373FK	Samples
SNJ54AHCT373J	ACTIVE	CDIP	J	20	20	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9686701QR A SNJ54AHCT373J	Samples
SNJ54AHCT373W	ACTIVE	CFP	W	20	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9686701QS A SNJ54AHCT373W	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

## PACKAGE OPTION ADDENDUM

www.ti.com 2-Dec-2024

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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#### OTHER QUALIFIED VERSIONS OF SN54AHCT373, SN74AHCT373:

Catalog: SN74AHCT373

Military: SN54AHCT373

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

## **PACKAGE MATERIALS INFORMATION**

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## TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AHCT373DBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74AHCT373DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74AHCT373NSR	SOP	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74AHCT373PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1
SN74AHCT373PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1



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#### \*All dimensions are nominal

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AHCT373DBR	SSOP	DB	20	2000	356.0	356.0	35.0
SN74AHCT373DWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74AHCT373NSR	SOP	NS	20	2000	367.0	367.0	45.0
SN74AHCT373PWR	TSSOP	PW	20	2000	356.0	356.0	35.0
SN74AHCT373PWR	TSSOP	PW	20	2000	353.0	353.0	32.0

## **PACKAGE MATERIALS INFORMATION**

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## **TUBE**



\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
5962-9686701Q2A	FK	LCCC	20	55	506.98	12.06	2030	NA
5962-9686701QSA	W	CFP	20	25	506.98	26.16	6220	NA
SN74AHCT373N	N	PDIP	20	20	506	13.97	11230	4.32
SNJ54AHCT373FK	FK	LCCC	20	55	506.98	12.06	2030	NA
SNJ54AHCT373W	W	CFP	20	25	506.98	26.16	6220	NA

## 14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

8.89 x 8.89, 1.27 mm pitch

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



## N (R-PDIP-T\*\*)

## PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOIC



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



# W (R-GDFP-F20)

## CERAMIC DUAL FLATPACK



- A. All linear dimensions are in inches (millimeters).
- This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.

  D. Index point is provided on cap for terminal identification only.

  E. Falls within Mil—Std 1835 GDFP2—F20







- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.







- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



## **MECHANICAL DATA**

## NS (R-PDSO-G\*\*)

# 14-PINS SHOWN

## PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



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